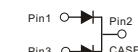
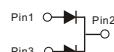
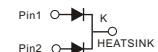


FEATURES

- Power pack
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL Level 1, per J-STD-020, LF MAX peak of 245°C (for TO-263 package)
- Solder bath temperature 275°C maximum, 10s, per JESD22-B106 (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2011/65/EU


TO-220AB
SR30100LCT

ITO-220AB
SRF30100LCT

TO-263
SR30100LD1


MECHANICAL DATA

- Case: JEDEC TO-220AB, ITO-220AB, TO-263
- Molding compound meets UL94V-0 flammability rating
- Terminals: Lead solderable per J-STD-002 and JESD22-B102
- Polarity: As marked
- Mounting Torque: 10 in-lbs maximum

TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified)

PRIMARY CHARACTERISTICS	
I _F (AV)	2×15A
V _{RRM}	100V
I _{FSM}	250A
V _F at I _f =5.0A,Per leg	0.48V
I _R	20 μ A
T _J (MAX)	150°C
Package	TO-220AB, ITO-220AB, TO-263
Diode variations	Common cathode

Parameter	Symbol	SR30100LCT, SRF30100LCT, SR30100LD1	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	100	V
Maximum average forward rectified current (see fig.1)	Per leg	15.0	A
	Total device	30.0	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _L)	I _{FSM}	250	A
Peak repetitive reverse current per diode at t _p =2 μ s 1KHz	I _{RRM}	0.5	A
Operating junction and Storage temperature range	T _J ,T _{Stg}	-55 to+150	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t=1 min	V _{AC}	1500	V

RATINGS AND CHARACTERISTIC OF SR30100LCT,SRF30100LCT,SR30100LD1

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Test Conditions		Symbol	TYP.	MAX.	Unit
Instantaneous forward voltage	Per leg $I_F=15.0\text{A}$	$T_A=25^\circ\text{C}$	V_F ¹⁾	0.69	0.71	V
		$T_A=100^\circ\text{C}$		0.67	—	
		$T_A=125^\circ\text{C}$		0.64	—	
		$T_A=25^\circ\text{C}$		0.50	0.52	
		$T_A=100^\circ\text{C}$		0.49	—	
	Per leg $I_F=5.0\text{A}$	$T_A=125^\circ\text{C}$		0.48	—	
		$T_A=25^\circ\text{C}$		20	50	$\mu\text{ A}$
		$T_A=100^\circ\text{C}$		2	5	mA
		$T_A=125^\circ\text{C}$		8	20	
Typical junction capacitance	4V, 1MHz		C_J	570		pF

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width $\leqslant 40\text{ms}$

THERMAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Symbol	SR30100LCT	SRF30100LCT	SR30100LD1	Unit
Typical thermal resistance ³⁾	$R_{\theta JC}$	2.5	4.5	2.5	$^\circ\text{C}/\text{W}$

3.Thermal resistance from junction to case

AVAILABALE PACK INFORMATION

Product code	Pack	Box Size L×W×H(mm)	Quantity(pcs/box)	Carton SizeL×W×H(mm)	Quantity(box/carton)
SR30100LCT-TO-220AB	P/T	558×148×38	1000	565×225×170	5
SRF30100LCT-ITO-220AB	P/T	558×148×38	1000	565×225×170	5
SR30100LD1-TO-263	P/T	558×148×38	1000	565×225×170	5

RATINGS AND CHARACTERISTIC OF SR30100LCT,SRF30100LCT,SR30100LD1

FIG.1-FORWARD CURRENT DERATING CURVE

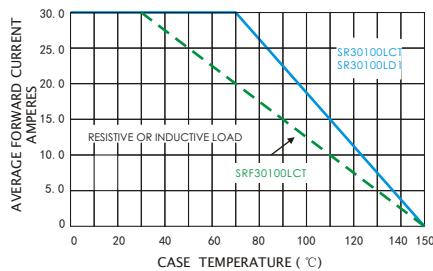


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

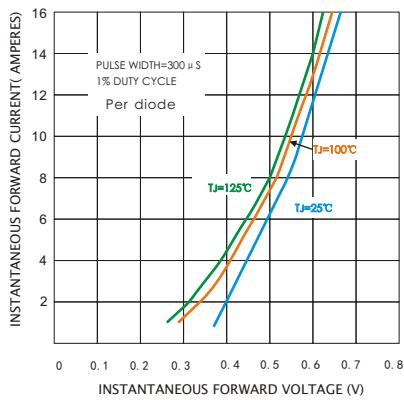


FIG.5-TYPICAL JUNCTION CAPACITANCE

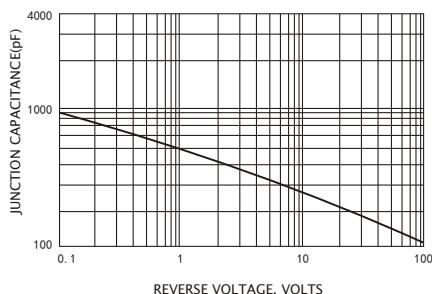


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

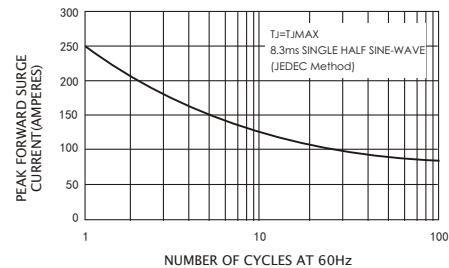
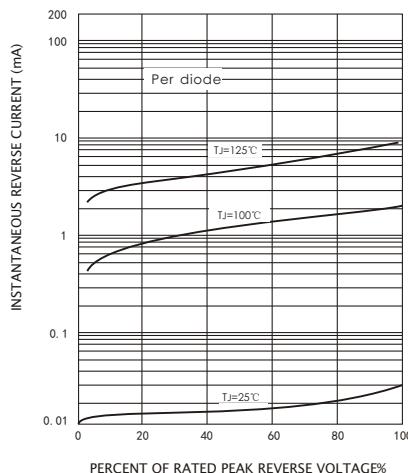
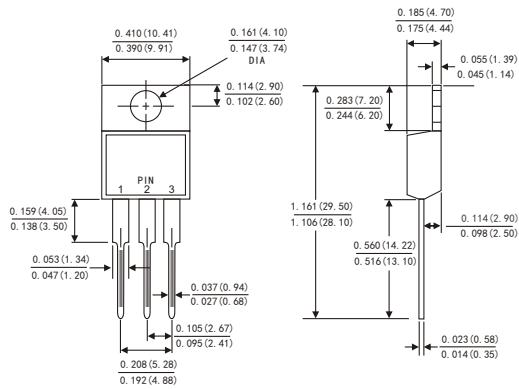


FIG.4-TYPICAL REVERSE CHARACTERISTICS

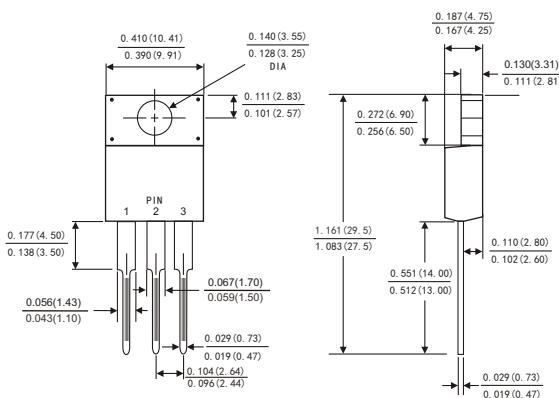


PACKAGE OUTLINE DIMENSIONS

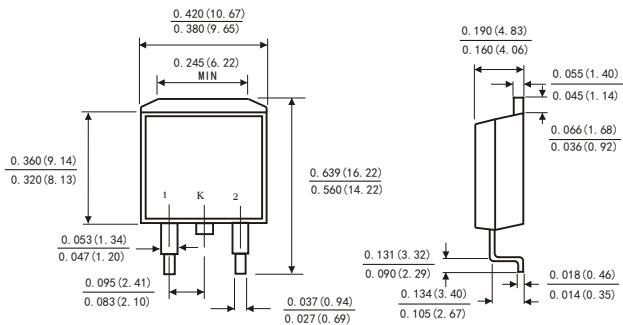
TO-220AB



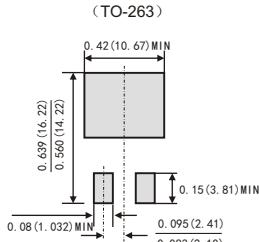
ITO-220AB



TO-263



Suggested Pad Layout



Dimensions in inches and (millimeters)